
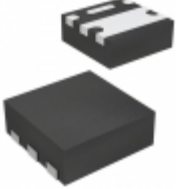

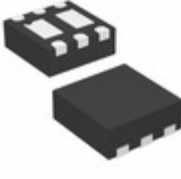

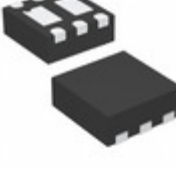


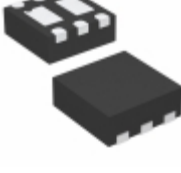
	<h2>SIA975DJ-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SIA975DJ-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET 2P-CH 12V 4.5A SC-70-6</p> <p>Datenblätter:  SIA975DJ-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 182200 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SIA975DJ-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET 2P-CH 12V 4.5A SC-70-6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	182200 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	7.8W
Verpackung / Gehäuse	PowerPAK® SC-70-6 Dual
Supplier Device-Gehäuse	PowerPAK® SC-70-6 Dual
Typ FET	2 P-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	12V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	4.5A
Rds On (Max) @ Id, Vgs	41 mOhm @ 4.3A, 4.5V
VGS (th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	26nC @ 8V
Eingabekapazität (Ciss) (Max) @ Vds	1500pF @ 6V
Verpackung	Tape & Reel (TR)














































SIA975DJ-T1-GE3 ist neu im Original. Suche SIA975DJ-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SIA975DJ-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SIA975DJ-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SIAA40DJ-T1-GE3 Vishay / Siliconix MOSFET N-CH 40V 30A SC70-6</p>	 <p>SIAERO+-EVb Energy Micro (Silicon Labs) BOARD EVAL FOR AERO+</p>	 <p>SIA950DJ-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 190V 0.95A SC-70-6</p>	 <p>SIA972DH-T1-GE3 VISHAY VISHAY SOT-363</p>
 <p>SIA936EDJ-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 20V 4.5A SC-70</p>	 <p>SIAA00DJ-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CHAN 25V</p>	 <p>SIAA40DJ-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 40V 30A SC70-6</p>	 <p>SIA936EDJ-T1-GE3 Vishay / Siliconix MOSFET 2N-CH 20V 4.5A SC-70</p>

heiße Teile

Mehr

 SIA906EDJ-T1-GE3	 SIA906EDJ-T1-GE3	 SIA906EDJ-T4-GE3	 SIA907EDJT	 SIA907EDJT-T1-GE3
 SIA907EDJT-T1-GE3	 SIA907EDJT-T4-GE3	 SIA910EDJ-T1-GE3	 SIA910EDJ-T1-GE3	 SIA911ADJ-T1-GE3
 SIA911ADJ-T1-GE3	 SIA911ADJ-T5-GE3	 SIA911DJ-T1-E3	 SIA911DJ-T1-E3	 SIA911DJ-T1-GE3
 SIA911DJ-T1-GE3	 SIA911DJ-T5-GE3	 SIA911EDJ-T1-GE3	 SIA911EDJ-T1-GE3	 SIA912DJ
 SIA912DJ-T1-GE3	 SIA912DJ-T1-GE3	 SIA913ADJ-T1-GE3	 SIA913ADJ-T1-GE3	 SIA913DJ-T1-GE3
 SIA913DJ-T1-GE3	 SIA914ADJ-T1-GE3	 SIA914ADJ-T1-GE3	 SIA914DJ-T1-GE3	 SIA914DJ-T1-GE3
 SIA915DJ-T1-GE3	 SIA915DJ-T1-GE3	 SIA917DJ-T1-GE3	 SIA917DJ-T1-GE3	 SIA920DJ-T1-GE3
 SIA920DJ-T1-GE3	 SIA921EDJ-T1-GE3	 SIA921EDJ-T1-GE3	 SIA921EDJ-T1/GE3	 SIA922EDJ-T1-GE3
 SIA922EDJ-T1-GE3	 SIA923AEDJ-T1-GE3	 SIA923AEDJ-T1-GE3	 SIA923EDJ-T1-GE3	 SIA923EDJ-T1-GE3
 SIA929DJ-T1-GE3	 SIA929DJ-T1-GE3	 SIA931DJ-T1-GE3	 SIA931DJ-T1-GE3	 SIA975DJ-T1-GE3

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